

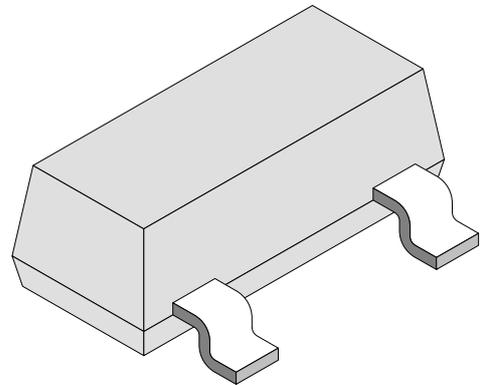
## Silicon NPN Phototransistor

### Description

TEMT2100 is a high speed silicon NPN epitaxial planar phototransistor in miniature SOT-23 package for surface mounting on printed boards. Due to its waterclear epoxy the device is sensitive to visible and near infrared radiation.

### Features

- Standard SOT-23 clear plastic package
- Extra wide viewing angle  $\varphi = \pm 70^\circ$
- Especially for surface mounting on printed board
- Small mechanical tolerances
- Fast response times
- Suitable for visible and near infrared radiation



94 8550

### Applications

Detector in electronic control and drive circuits in SMD technique

### Absolute Maximum Ratings

$T_{amb} = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Collector Emitter Voltage		$V_{CEO}$	70	V
Emitter Collector Voltage		$V_{ECO}$	5	V
Collector Current		$I_C$	50	mA
Peak Collector Current	$t_p/T = 0.5, t_p \leq 10 \text{ ms}$	$I_{CM}$	100	mA
Total Power Dissipation	$T_{amb} \leq 25^\circ\text{C}$	$P_{tot}$	75	mW
Junction Temperature		$T_j$	100	$^\circ\text{C}$
Storage Temperature Range		$T_{stg}$	-55...+100	$^\circ\text{C}$
Soldering Temperature	$t \leq 5 \text{ s}$	$T_{sd}$	260	$^\circ\text{C}$
Thermal Resistance Junction/Ambient		$R_{thJA}$	1000	K/W

## Basic Characteristics

$T_{amb} = 25^{\circ}\text{C}$

Parameter	Test Conditions	Symbol	Min	Typ	Max	Unit
Collector Emitter Breakdown Voltage	$I_C = 1\text{ mA}$	$V_{(BR)CEO}$	70			V
Collector Dark Current	$V_{CE} = 20\text{ V}, E = 0$	$I_{CEO}$		1	200	nA
Collector Emitter Capacitance	$V_{CE} = 5\text{ V}, f = 1\text{ MHz}, E=0$	$C_{CEO}$		3		pF
Collector Light Current	$E_c=1\text{mW/cm}^2, \lambda=950\text{nm}, V_{CE}=5\text{V}$	$I_{ca}$	0.30	0.45		mA
Angle of Half Sensitivity		$\phi$		$\pm 70$		deg
Wavelength of Peak Sensitivity		$\lambda_p$		850		nm
Range of Spectral Bandwidth		$\lambda_{0.5}$		620...980		nm
Collector Emitter Saturation Voltage	$E_c=1\text{mW/cm}^2, \lambda=950\text{nm}, I_C=0.1\text{mA}$	$V_{CEsat}$			0.3	V
Turn-On Time	$V_S=5\text{V}, I_C=5\text{mA}, R_L=100\Omega$	$t_{on}$		2.0		$\mu\text{s}$
Turn-Off Time	$V_S=5\text{V}, I_C=5\text{mA}, R_L=100\Omega$	$t_{off}$		2.3		$\mu\text{s}$
Cut-Off Frequency	$V_S=5\text{V}, I_C=5\text{mA}, R_L=100\Omega$	$f_c$		180		kHz

## Typical Characteristics ( $T_{amb} = 25^{\circ}\text{C}$ unless otherwise specified)

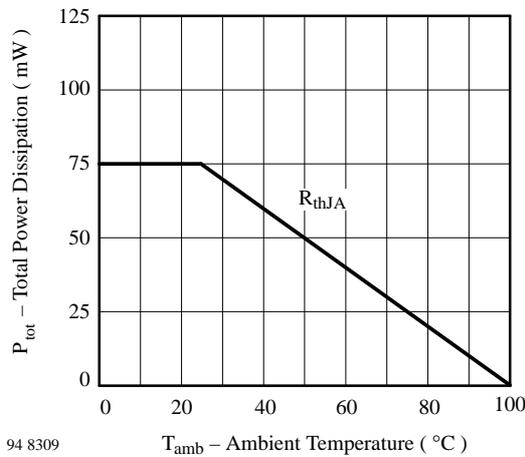


Figure 1. Total Power Dissipation vs. Ambient Temperature

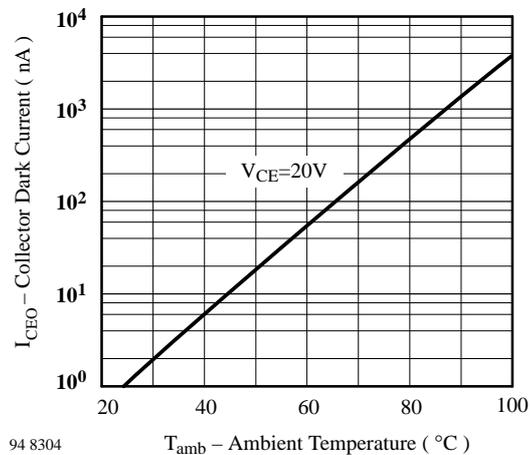


Figure 2. Collector Dark Current vs. Ambient Temperature

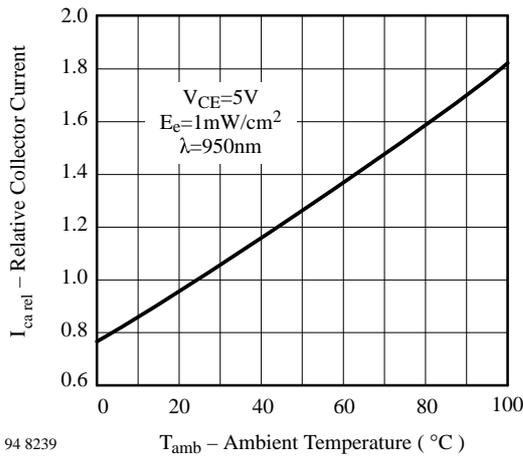


Figure 3. Relative Collector Current vs. Ambient Temperature

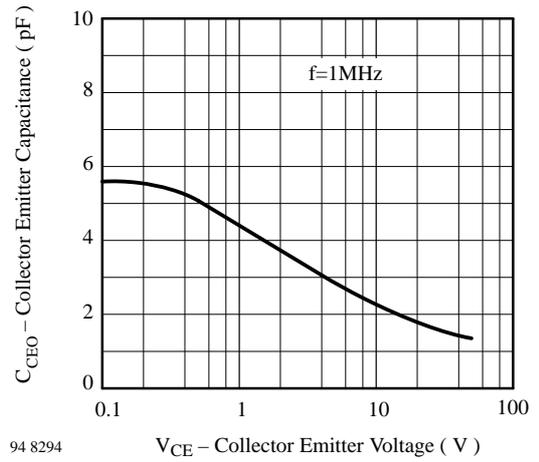


Figure 6. Collector Emitter Capacitance vs. Collector Emitter Voltage

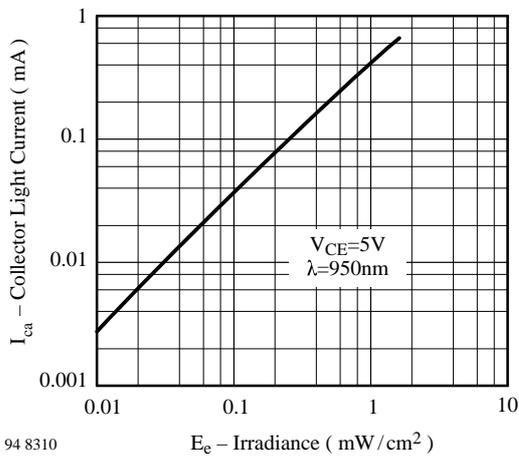


Figure 4. Collector Light Current vs. Irradiance

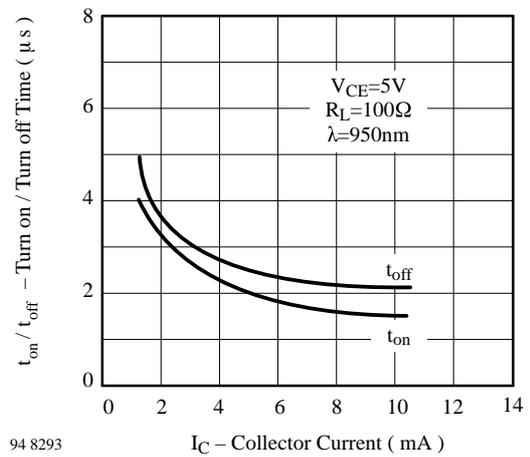


Figure 7. Turn On/Turn Off Time vs. Collector Current

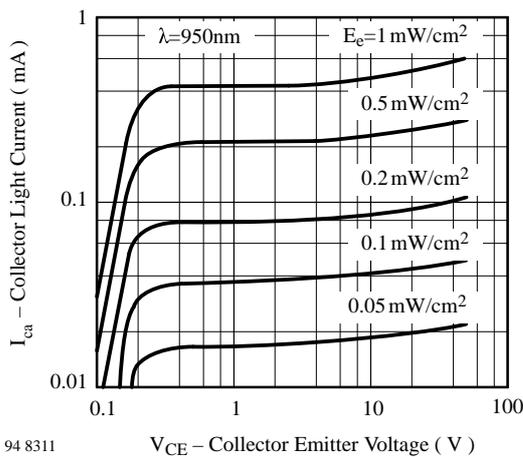


Figure 5. Collector Light Current vs. Collector Emitter Voltage

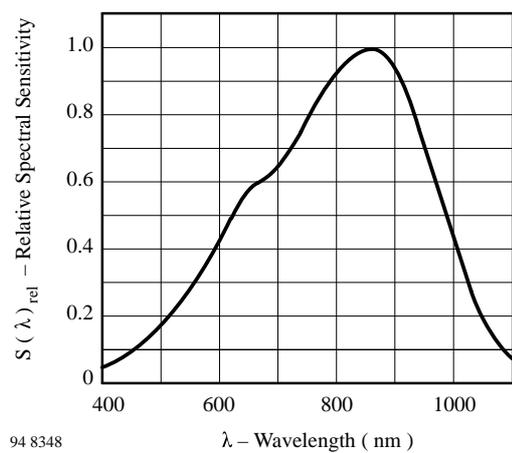
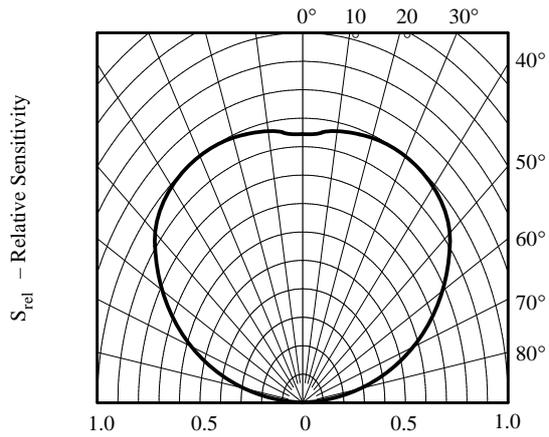


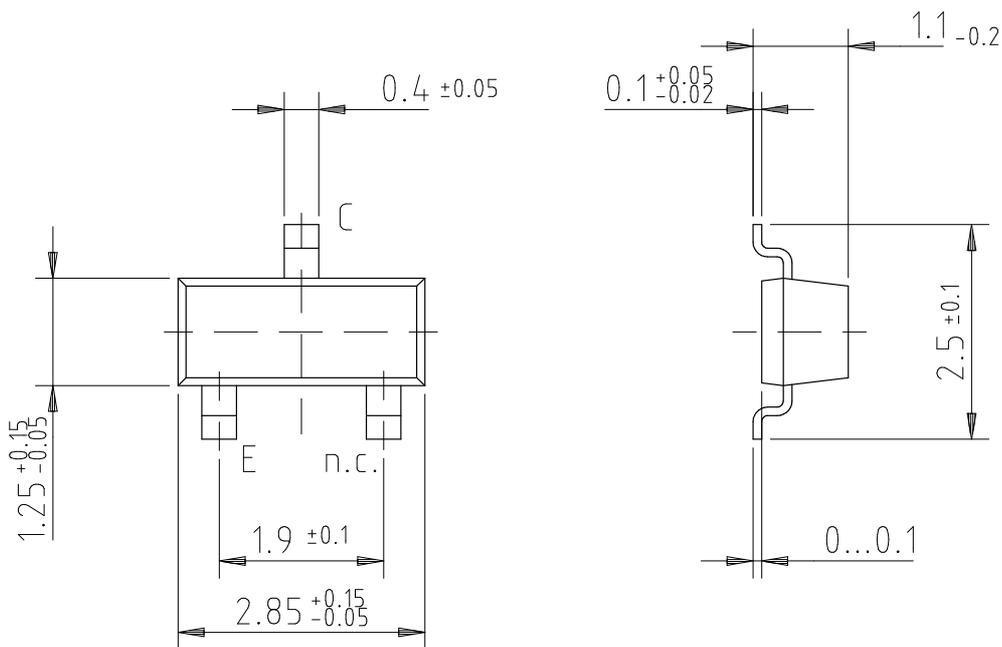
Figure 8. Relative Spectral Sensitivity vs. Wavelength



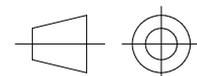
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Figure 9. Relative Radiant Sensitivity vs. Angular Displacement

## Dimensions in mm



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technical drawings  
according to DIN  
specifications

## **Ozone Depleting Substances Policy Statement**

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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